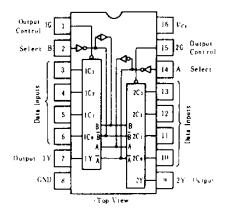
This data selector/multiplexer contains inverters and drivers to supply fully complementary, on-chip, binary decoding data selection to AND-OR gates.

Separate output control inputs are provided for each of the two four-line sections. The three-state outputs can interface with and drive data lines of bus-organized systems. With all but one of the common outputs disabled (at high-impedance state) the low-impedance of the single enabled output will dirve the bus line to a high or low logic level.

PIN ARRANGEMENT



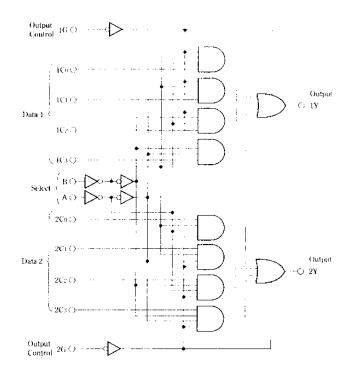
IFUNCTION TABLE

	Select inputs		Data	inputs		Output control	Output
В	Α	Со	Cı	C ₂	C ₃	G	Y
×	×	×	Х	×	×	Н	Z
L	L	L	Х	×	×	L	L,
L	L	Н	×	×	×	L	H
L	Н	×	L	×	×	L	L
L	Н	×	Н	×	×	L	Н
H	L	×	_ ×	L	×	L	L
Н	L	×	×	Н	×	L	Н
Н	Н	×	×	×	L	L	L
H	Н	×	×	×	Н	L	Н

Notes) 1. H; high level, L; low level, X; irrelevant

2. Address inputs A and B are common to both sections.

■BLOCK DIAGRAM



MADSOLUTE MAXIMUM RATINGS

ltem	Symbol	Ratings	Unit	
Supply voltage	Vcc	7.0	V	
Input voltage	V_{IN}	7.0	V	
Output voltage (off-state)	Vo(off)	5.5	V	
Operating temperature range	Top,	20~ + 75	•C	
Storage temperature range	Tale	-65-+150	c	

ELECTRICAL CHARACTERISTICS ($Ta = -20 \sim +75$ °C)

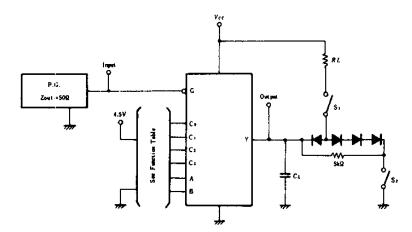
Item	Symbol	Test Conditions		min	typ*	max	Unjt
_	VIH			2.0	_		V
Input voltage	VIL			_	_	0.8	V
	Voн	Vcc=4.75V, VIH=2V, VIL=0.8	I, Іон = -2.6mA	2.4			V
Output voltage	Vol	$V_{CC} = 4.75V$, $V_{IH} = 2V$,	IoL = 4mA	_		0.4	v
		$V_{IL}=0.8V$	$I_{OL} = 8 \text{mA}$	_		0.5	V
	Irn	$V_{CC} = 5.25 \text{V}, V_I = 2.7 \text{V}$	•		-	20	μA
Input current	ItL	$V_{CC} = 5.25 \text{V}, V_I = 0.4 \text{V}$	_		-0.4	mA	
	Iı	$V_{CC} = 5.25 \text{V}, V_I = 7 \text{V}$		_		0.1	mA
_	Ioz	$V_{CC}=5.25V, V_{IH}=2V$	$V_0 = 2.7 \text{V}$			20	μA
Output current			Vo=0.4V	_		20	
Short-circuit output current	Ios	Vcc=5.25V		-30		-130	mA
	rent** Icc	Vcc=5.25V ConditionA		_	7	12	mA
Supply current**				+	8.5	14	
Input clamp voltage	VIK	$V_{CC} = 4.75 \text{V}, I_{IN} = -18 \text{mA}$			_	-1.5	v

ESWITCHING CHARACTERISTICS ($V_{CC} = 5V$, $T_a = 25^{\circ}C$)

Item	Inputs	Output	Symbol	Test Conditions	min	typ	max	Unit
	Data	Y	tPLH		. –	17	25	
			tPHL		_	13	20	
Propagation delay time	Select	Y	tplH	$C_L = 15 pF$	_	30	45	ns
			tPHL.	$R_L = 2k \Omega$	_	21	32	
Output enable time	Output	Y	tzH	-		15	28	ns
	Control		tzı		_	15	23	
	Output	Y	thz	$C_L = 5 pF$	_	27	41	ns
Output disable time	Control		ILZ	$R_L = 2k \Omega$	_	18	27	

TESTING METHOD

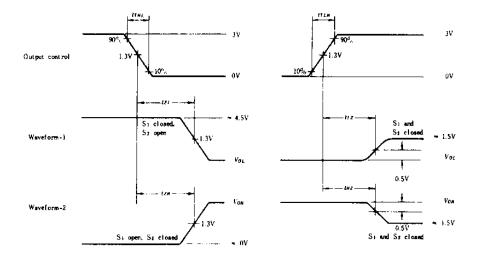
1) Test Circuit



^{*} VCC=5V, Ta=25°C
** ICC is measured with the outputs open under the following conditions: A. All inputs grounded, B. Output control at 4.5V, all inputs grounded.

HD74LS253

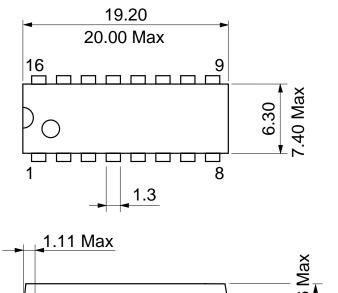
Waveform

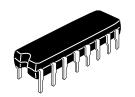


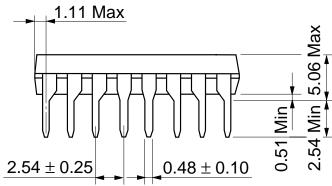
- Notes) 1. Input pulse: $t_{TLH} \le 15$ ns, $t_{THL} \le 6$ ns, PRR = 1MHz, duty cycle = 50%.
 - C_I, includes probe and jig capacitance.
 All diodes are 1S2074 ①.

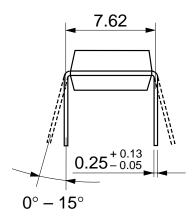
 - 4. Waveform-1 is for an output with internal conditions such that the output is low except when disabled by the output control.
 - 5. Waveform-2 is for an output with internal conditions such that the output is high except when disabled by the output control.

Unit: mm



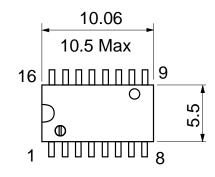


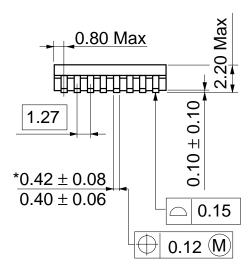




Hitachi Code	DP-16
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	1.07 g

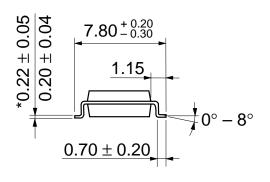
Unit: mm





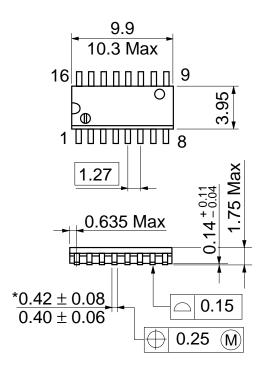
*Dimension including the plating thickness
Base material dimension



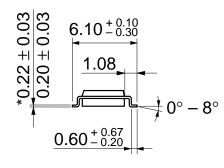


Hitachi Code	FP-16DA
JEDEC	
EIAJ	Conforms
Weight (reference value)	0.24 g

Unit: mm







*Dimension including the plating thickness
Base material dimension

Hitachi Code	FP-16DN
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.15 g

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